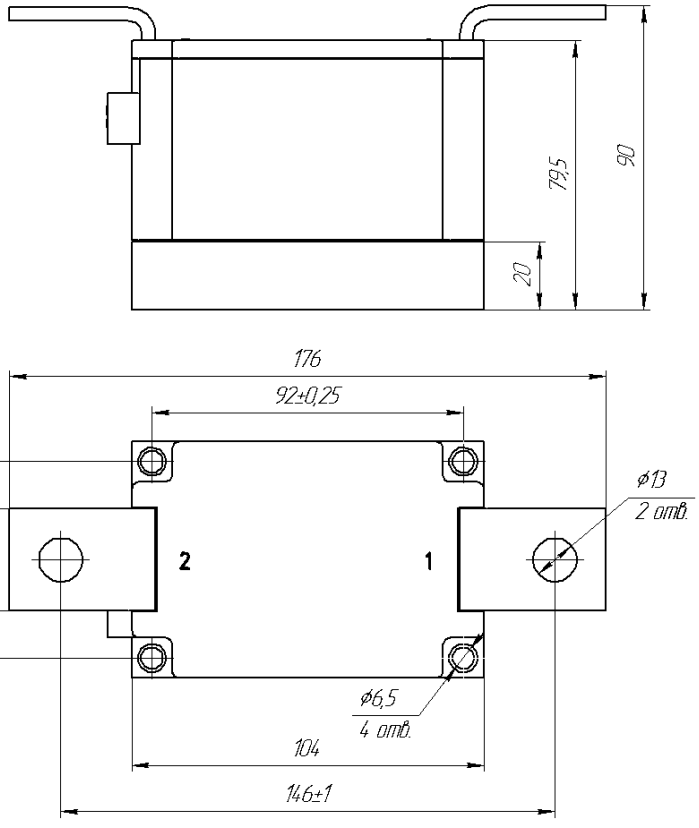
Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

Single Diode Module For Phase Control MD1-1000-44-E

Average forward current		I_{FAV}	1000 A	
Repetitive peak reverse voltage		V_{RRM}	3800 ÷ 4400 V	
V_{RRM}, V	3800	4000	4200	4400
Voltage code	38	40	42	44
T_j, °C	- 40 ÷ 160			

MD1



All dimensions in millimeters (inches)

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	1000	T_c= 95 °C; 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	1570	T_c= 95 °C; 180° half-sine wave; 50 Hz	
I_{FSM}	Surge forward current	kA	34.0 41.0	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=10 ms; single pulse; V_R=0 V;
			36.0 43.0	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=8.3 ms; single pulse; V_R=0 V;
I^2t	Safety factor	$A^2s\cdot10^3$	5700 8400	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=10 ms; single pulse; V_R=0 V;
			5300 7600	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=8.3 ms; single pulse; V_R=0 V;
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	3800÷4400	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; 50 Hz;	
V_{RSM}	Non-repetitive peak reverse voltages	V	3900÷4500	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; single pulse;	
V_R	Reverse continuous voltages	V	0.6·V_{RRM}	T_j=$T_{j\,max}$;	
THERMAL					
T_{stg}	Storage temperature	°C	- 40 ÷ 50		
T_j	Operating junction temperature	°C	- 40 ÷ 160		
$T_{c\,op}$	Operating temperature	°C	- 40 ÷ 125		
MECHANICAL					
a	Acceleration under vibration	m/s^2	50		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V_{FM}	Peak forward voltage, max	V	1.50	T_j=25 °C; I_{FM}= 2512 A	
$V_{F(TO)}$	Forward threshold voltage, max	V	0.85	T_j=$T_{j\,max}$; 0.5 π I_{FAV} < I_T < 1.5 π I_{FAV}	
r_T	Forward slope resistance, max	mΩ	0.280		
BLOCKING					
I_{RRM}	Repetitive peak reverse current, max	mA	100	T_j=$T_{j\,max}$; V_R=V_{RRM}	
SWITCHING					
Q_{rr}	Total recovered charge, max	μC	5550	T_j=$T_{j\,max}$; I_{FM}= 475 A; dI_{FM}/dt=-5 A/μs; V_R=100 V	
t_{rr}	Reverse recovery time, max	μs	73		
I_{rrM}	Peak reverse recovery current, max	A	152		
THERMAL					
R_{thjc}	Thermal resistance, junction to case				
	per module	°C/W	0.0420	180° half-sine wave, 50 Hz	
R_{thch}	Thermal resistance, case to heatsink				
	per module	°C/W	0.0100		
INSULATION					
V_{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS	t=60 sec
			3.60		t=1 sec
MECHANICAL					
M_1	Mounting torque (M6)[1)]	Nm	6.00	Tolerance ± 15%	
M_2	Terminal connection torque (M12)[1)]	Nm	18.00	Tolerance ± 15%	
w	Weight, max	g	2250		

PART NUMBERING GUIDE	NOTES
MD 1 - 1000 - 44 - E - N 1 2 3 4 5 6 1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.E) 6. Ambient Conditions: N – Normal	[1)] The screws must be lubricated
UL certified file-No. E255404	

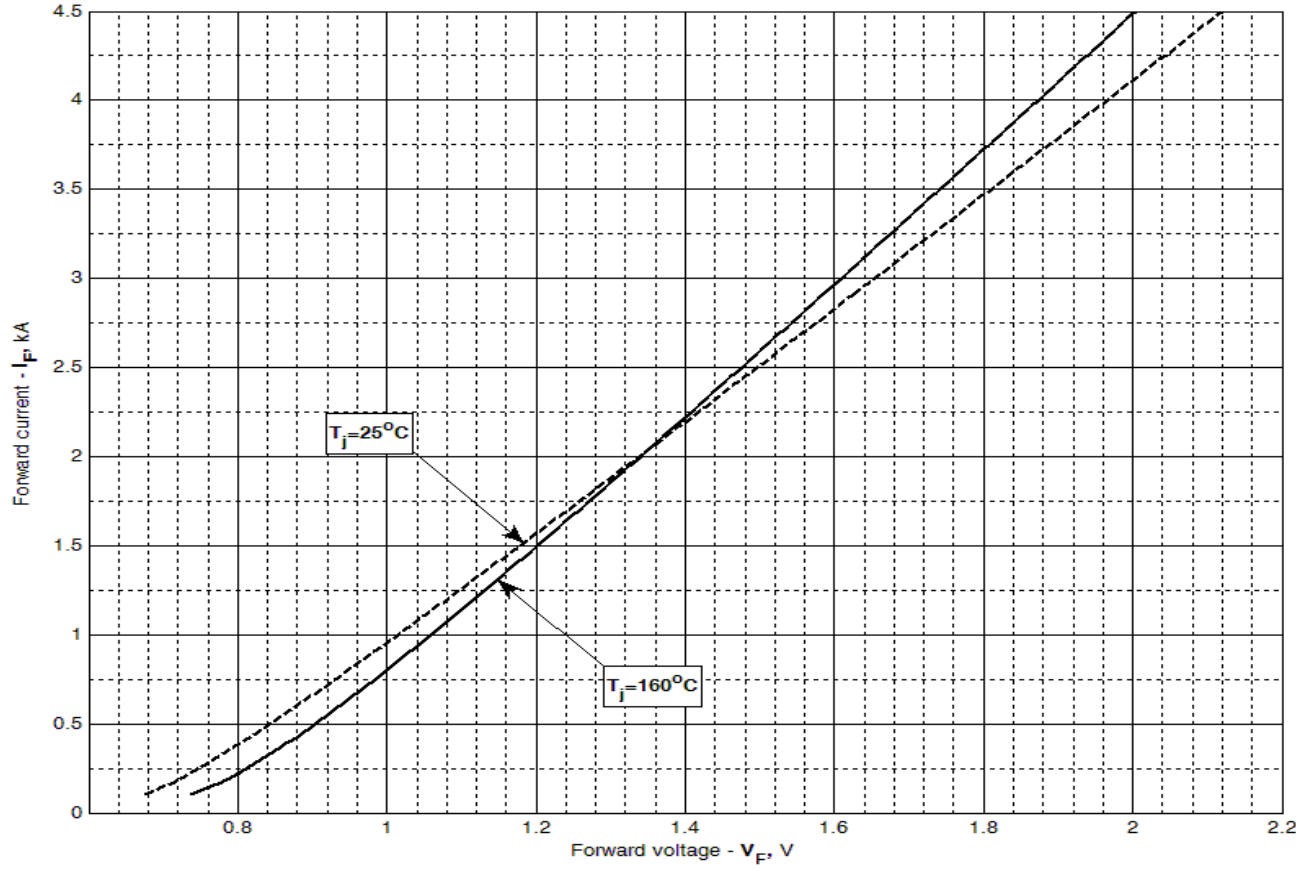


Fig 1 – Forward characteristics of Limit device

Analytical function for Forward characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	T_j = 25°C	$T_j = T_{j\,max}$
A	0.579461	0.615440
B	0.274124	0.209316
C	-0.148778	-0.216178
D	0.264245	0.383954

Forward characteristic model (see Fig. 1)

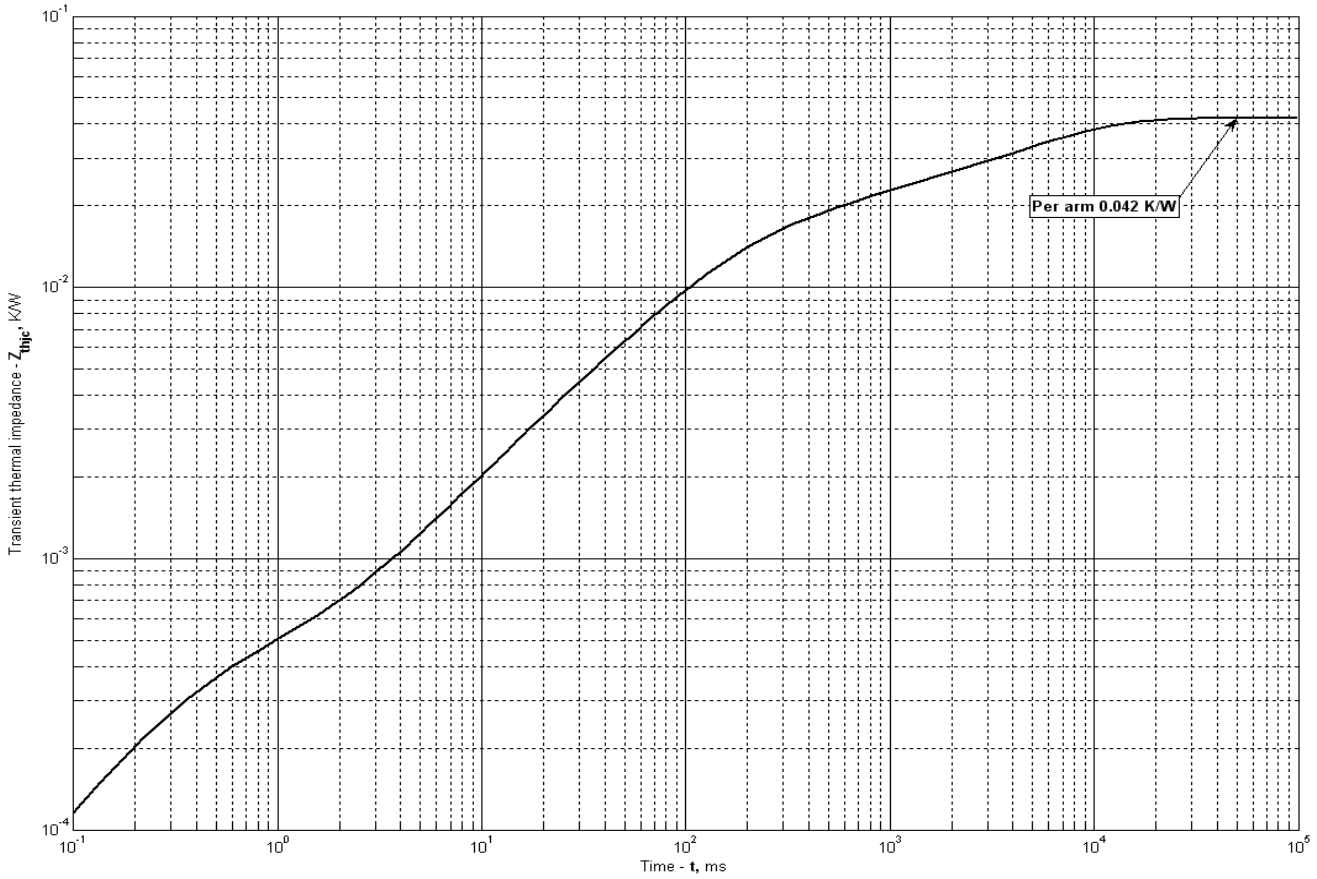


Fig 2 – Transient thermal impedance

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^{n} R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where ***i*** = 1 to ***n***, ***n*** is the number of terms in the series.

t = Duration of heating pulse in seconds.

$\mathbf{Z_{thjc}}$ = Thermal resistance at time t.

$\mathbf{R_i}$ = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

i	1	2	3	4	5	6
$\mathbf{R_i}$**, K/W**	0.02105	0.005931	0.009502	0.004252	0.001006	0.0003132
τ_i**, s**	5.887	0.7389	0.1616	0.08215	0.01267	0.0002712

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

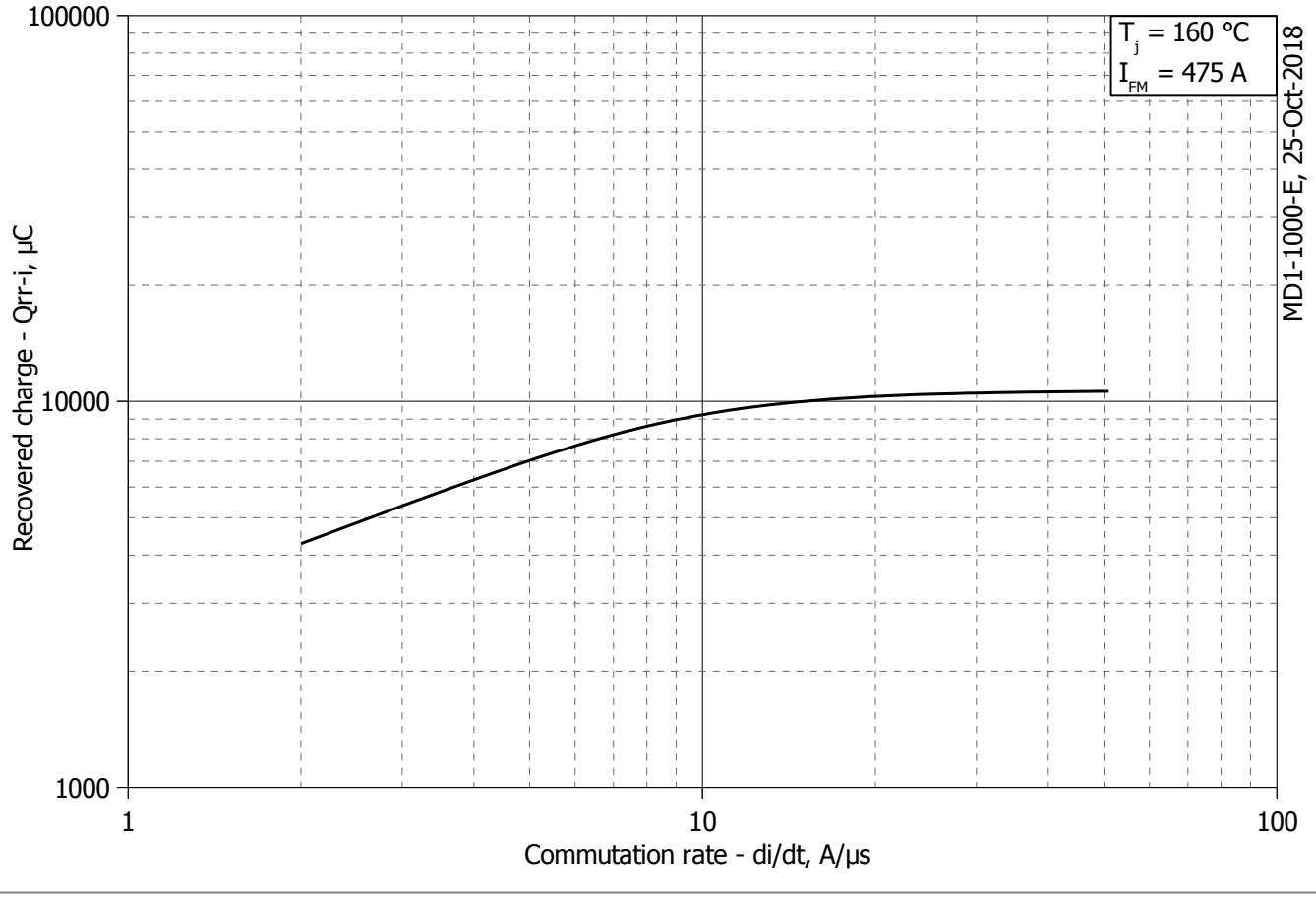


Fig 3 – Total recovered charge, Q_{rr-i} (integral)

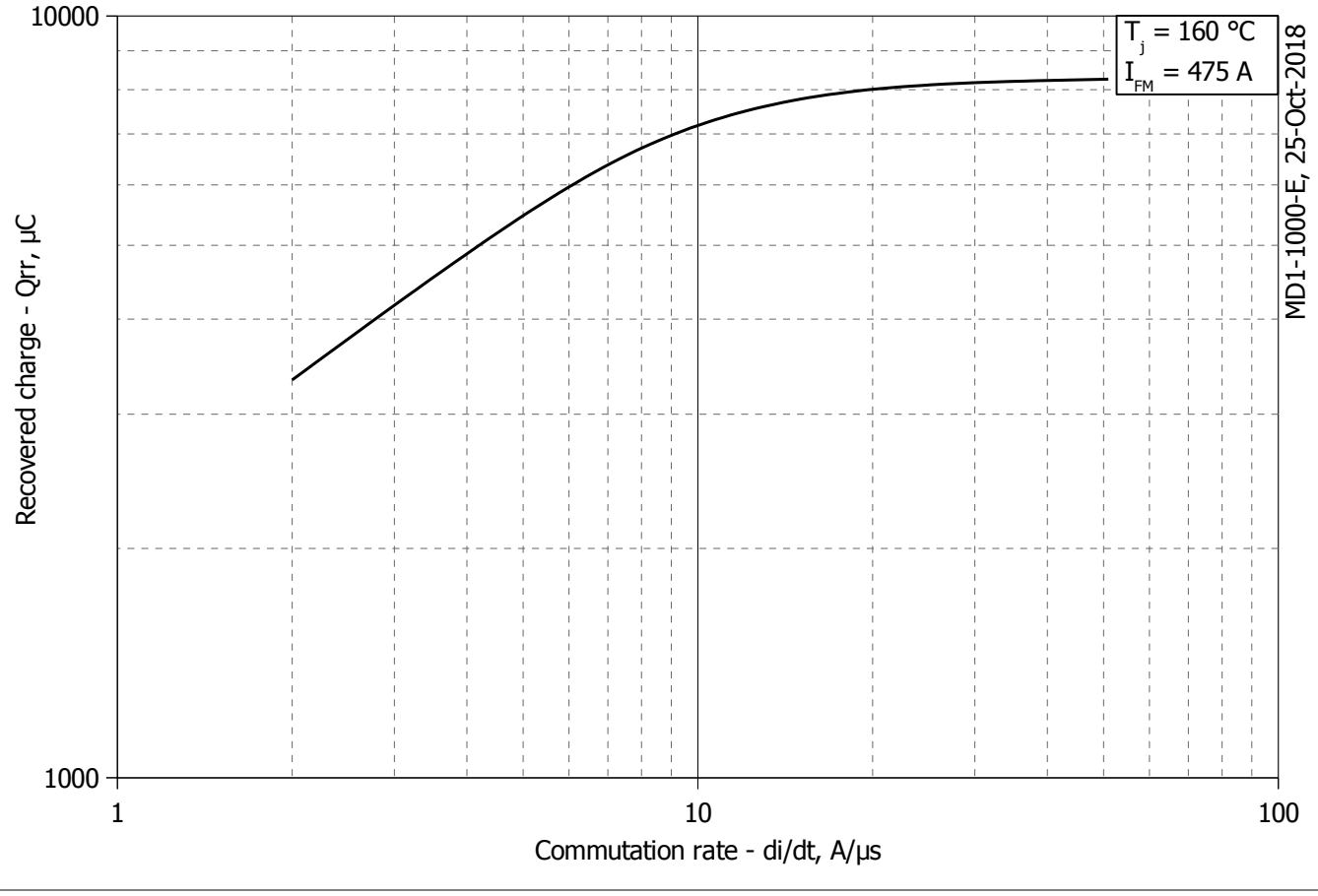


Fig 4 - Recovered charge, Q_{rr} (25% chord)

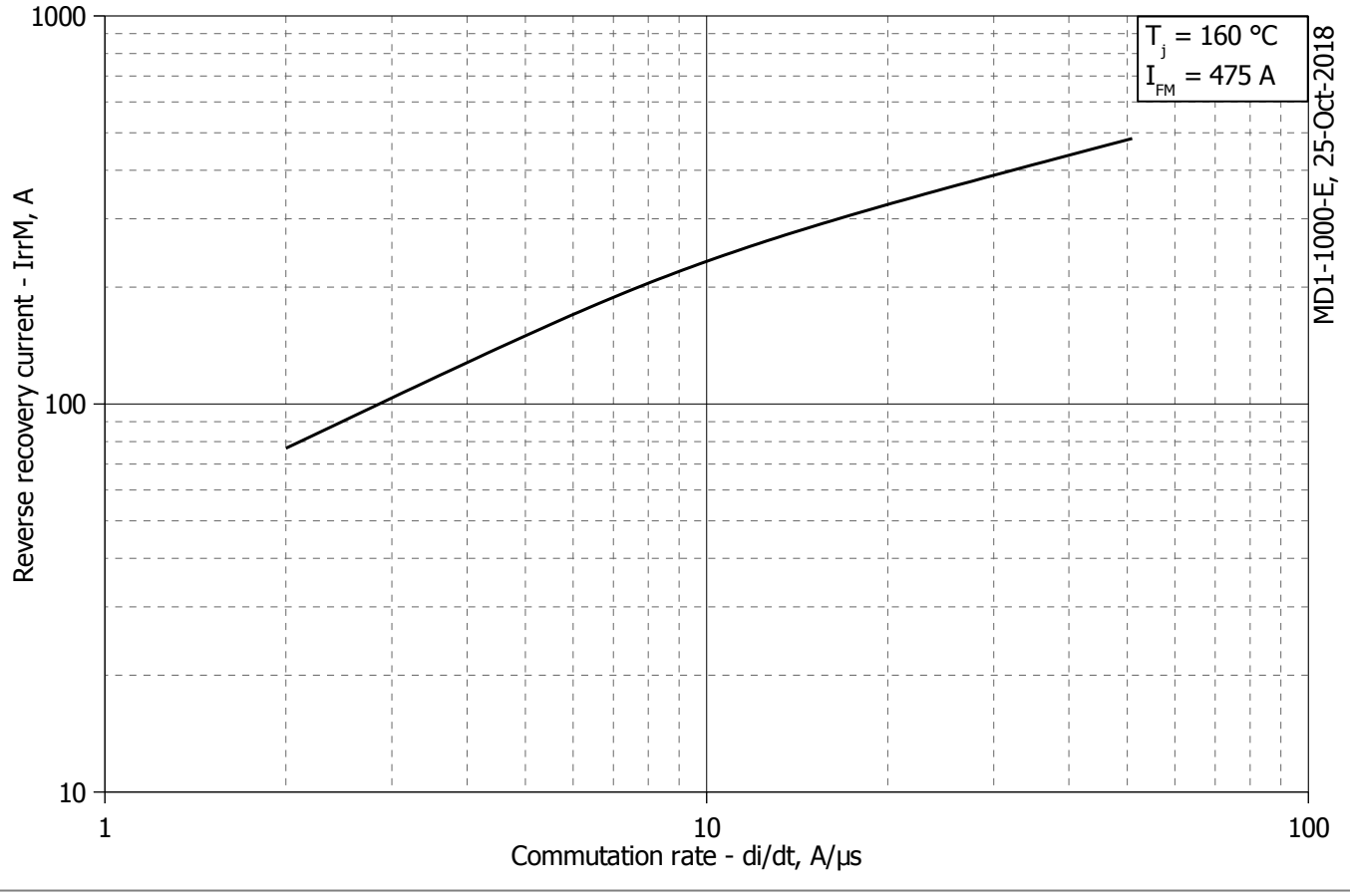


Fig 5 – Peak reverse recovery current, I_{rrM}

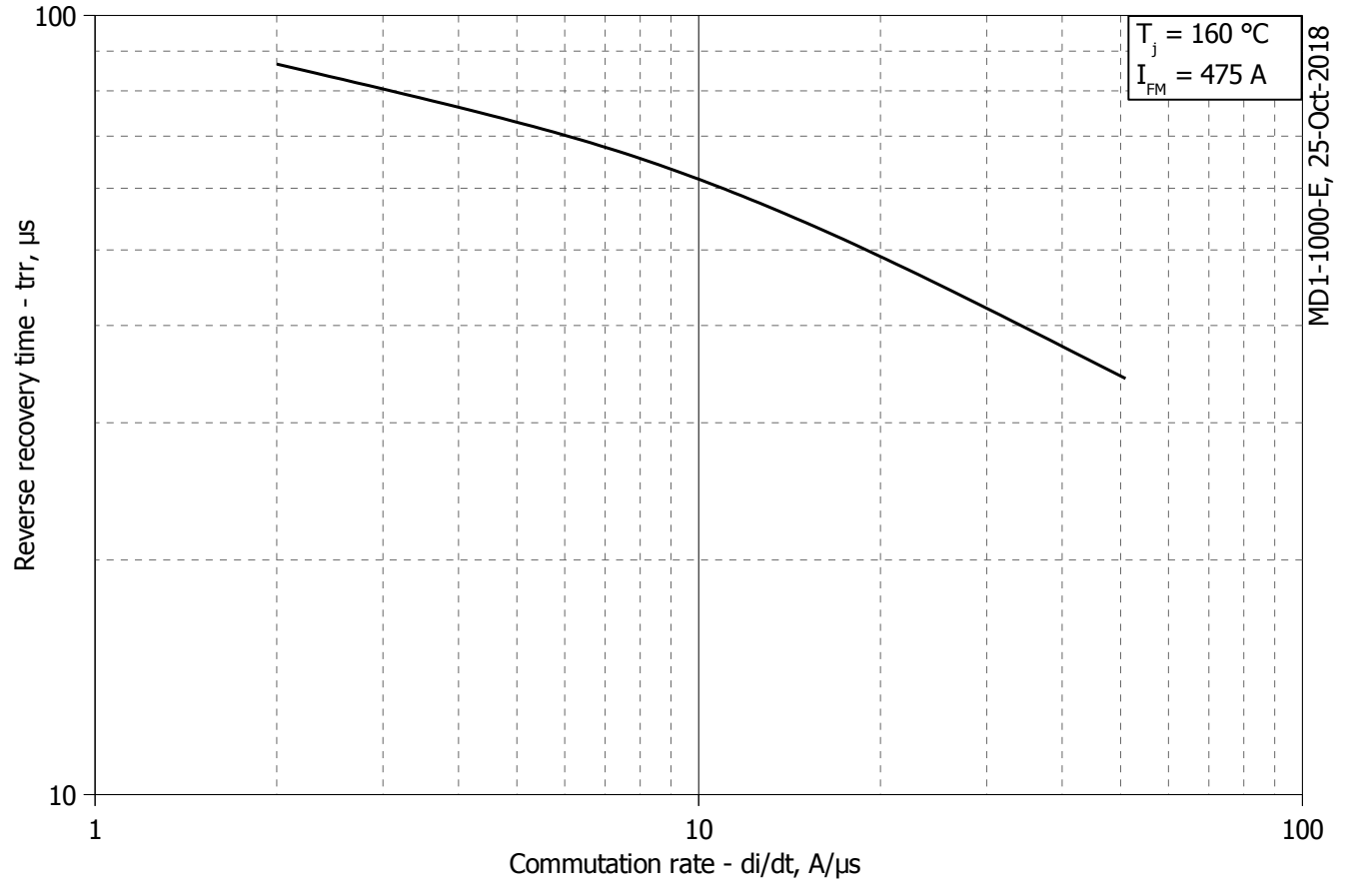


Fig 6 – Maximum recovery time, t_{rr} (25% chord)

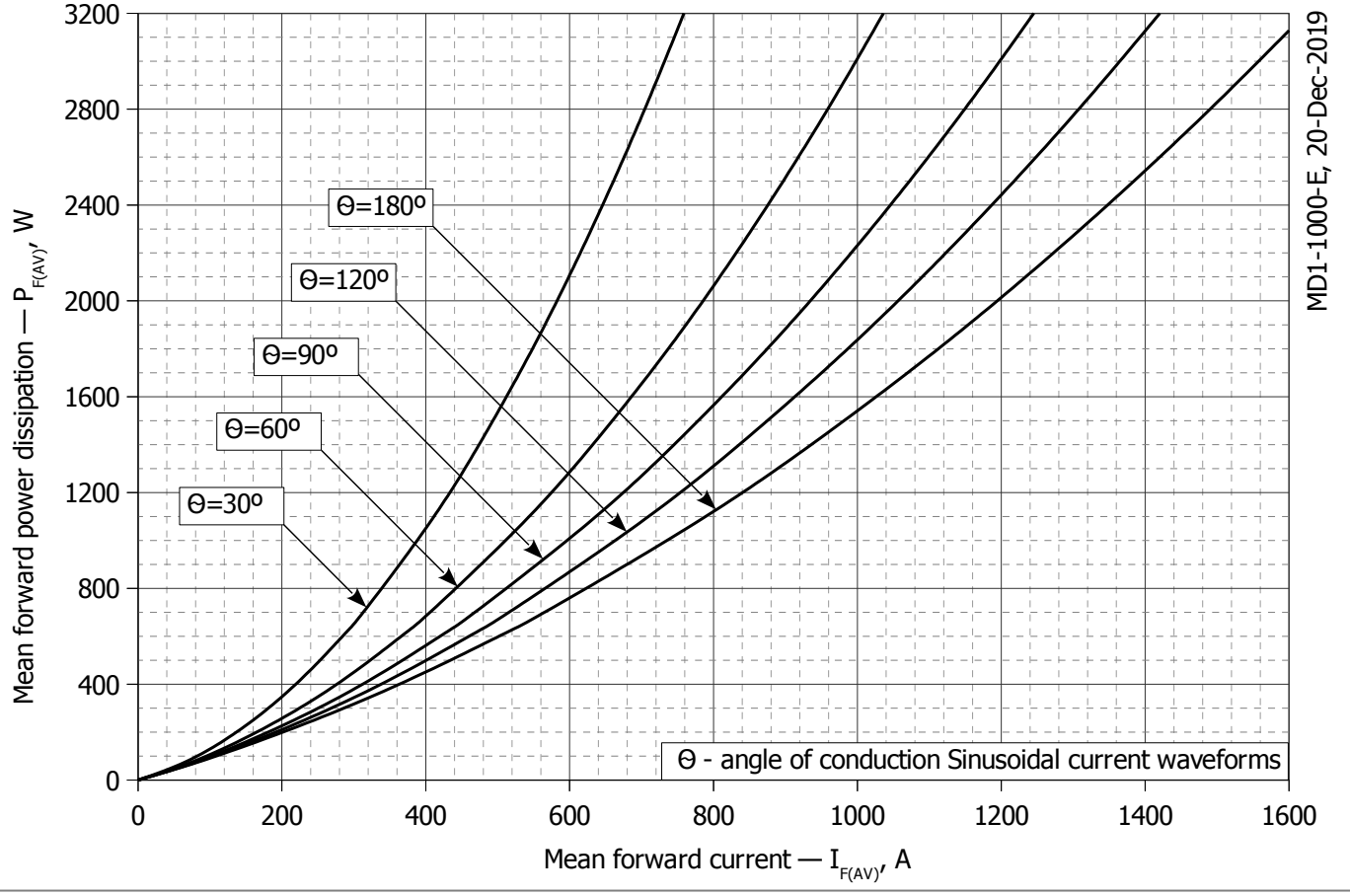


Fig 7 – Mean forward power dissipation P_{FAV} vs. Mean forward current I_{FAV} for sinusoidal current waveforms at different conduction angles

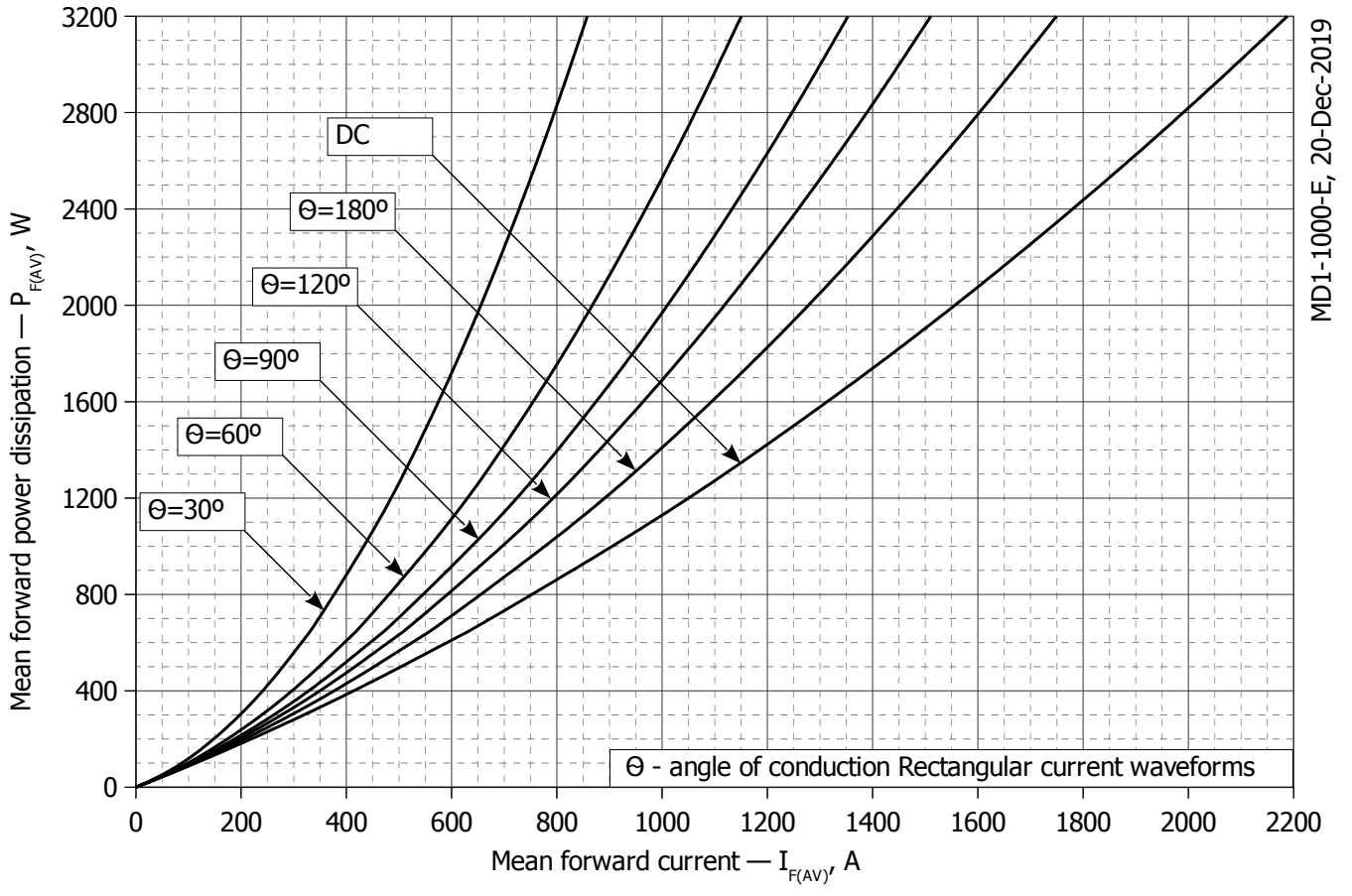


Fig 8 – Mean forward power dissipation P_{FAV} vs. Mean forward current I_{FAV} for rectangular current waveforms at different conduction angles and for DC

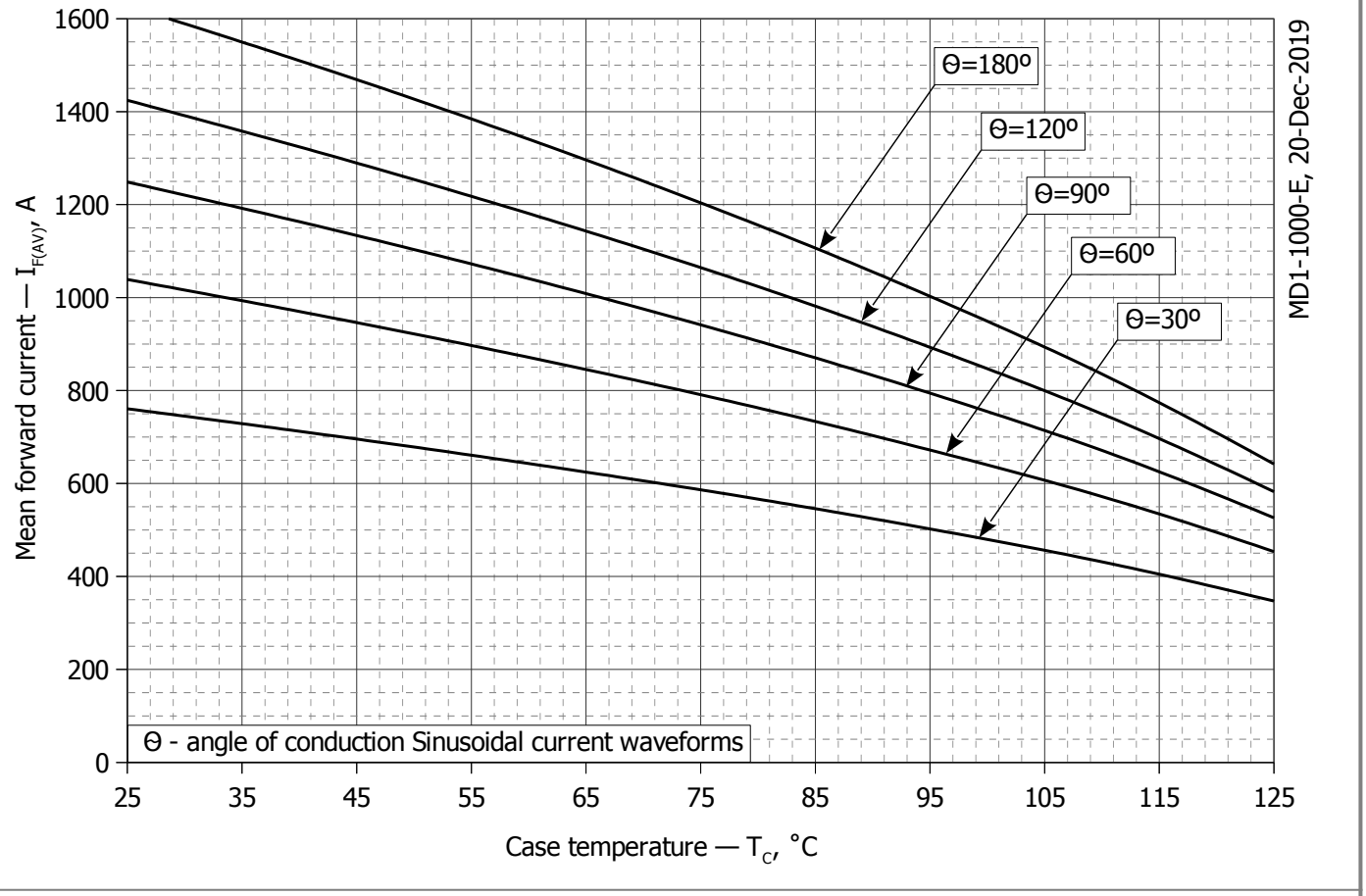


Fig 9 – Mean forward current I_{FAV} vs. Case temperature T_C for sinusoidal current waveforms at different conduction angles

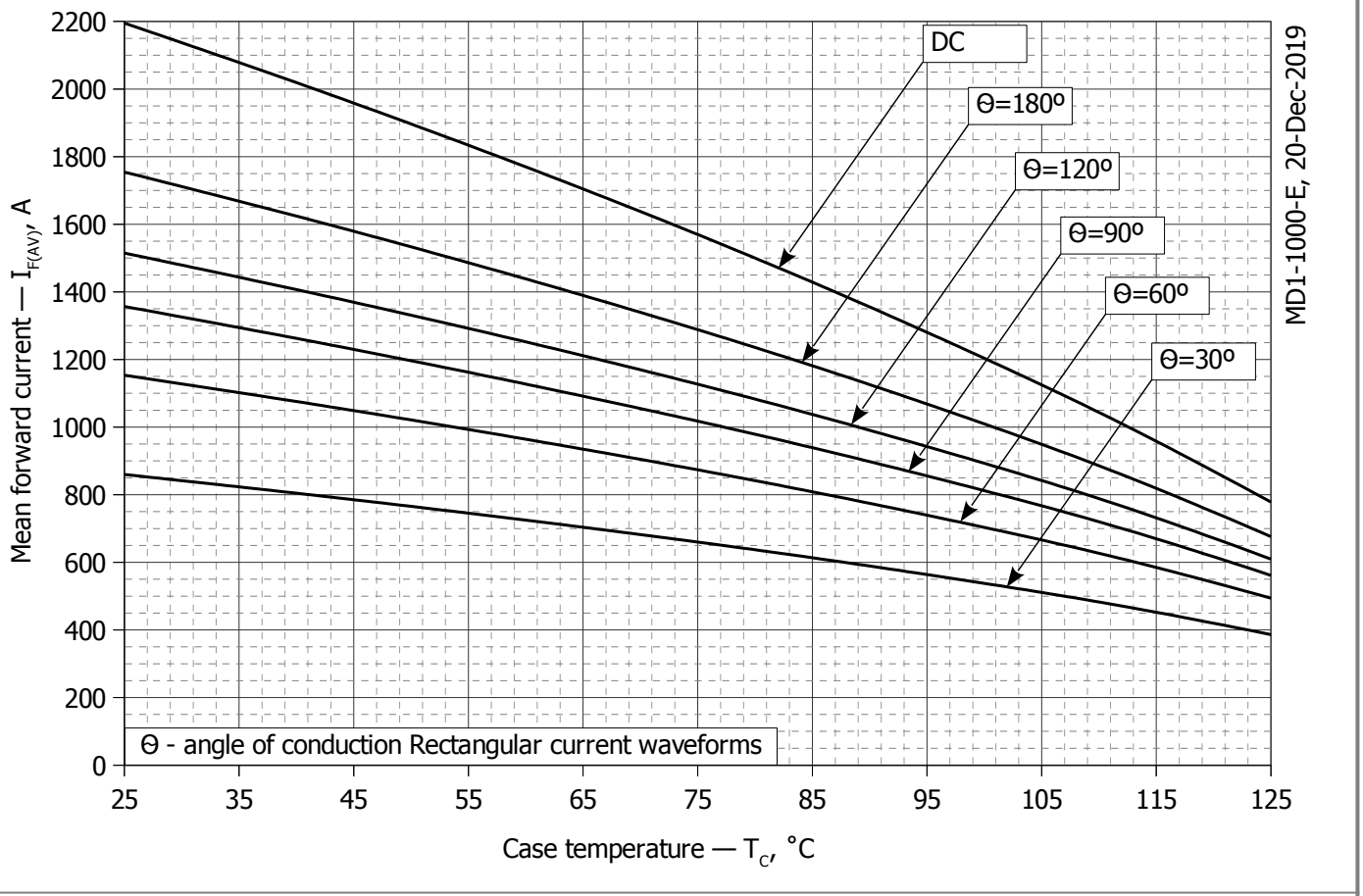


Fig 10 – Mean forward current I_{FAV} vs. Case temperature T_C for rectangular current waveforms at different conduction angles and for DC

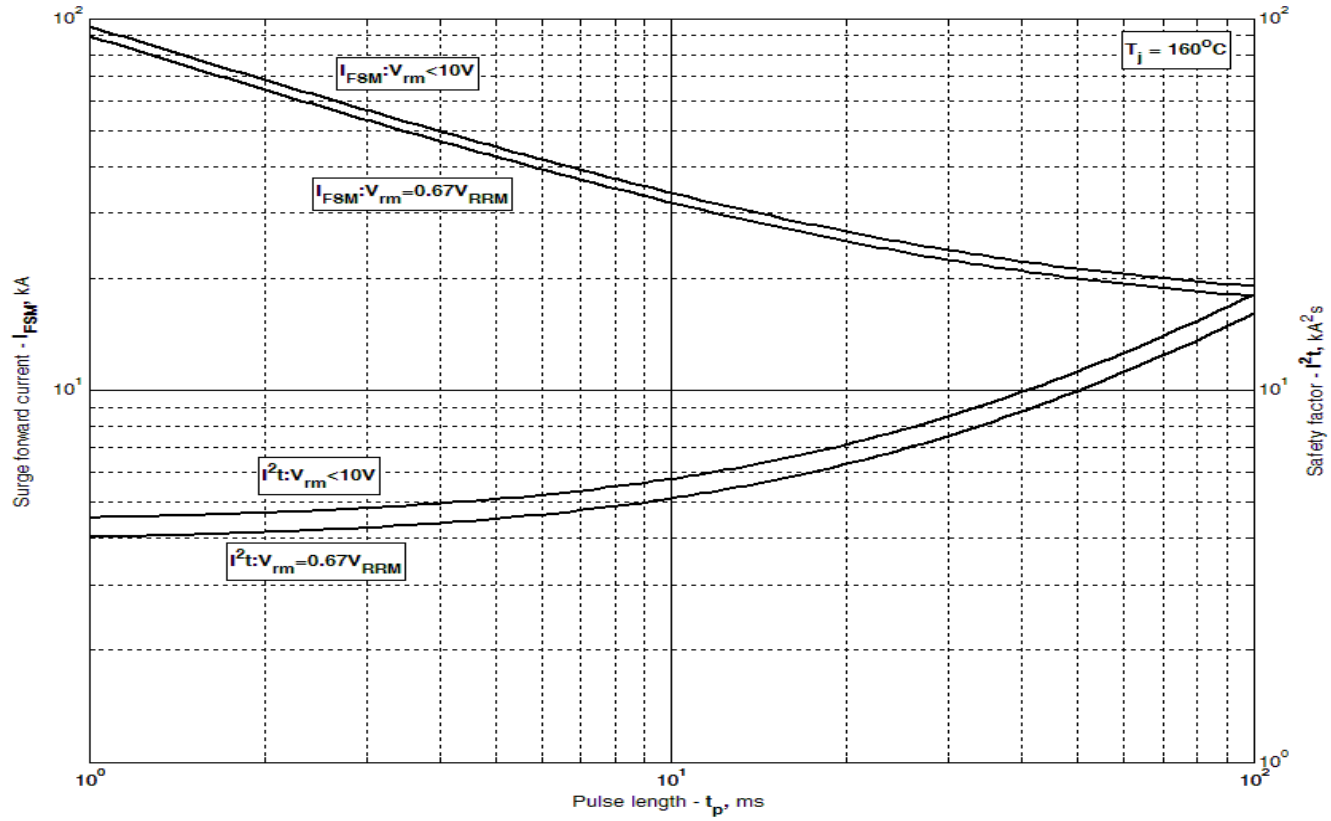


Fig 11 – Maximum surge and I^2t ratings

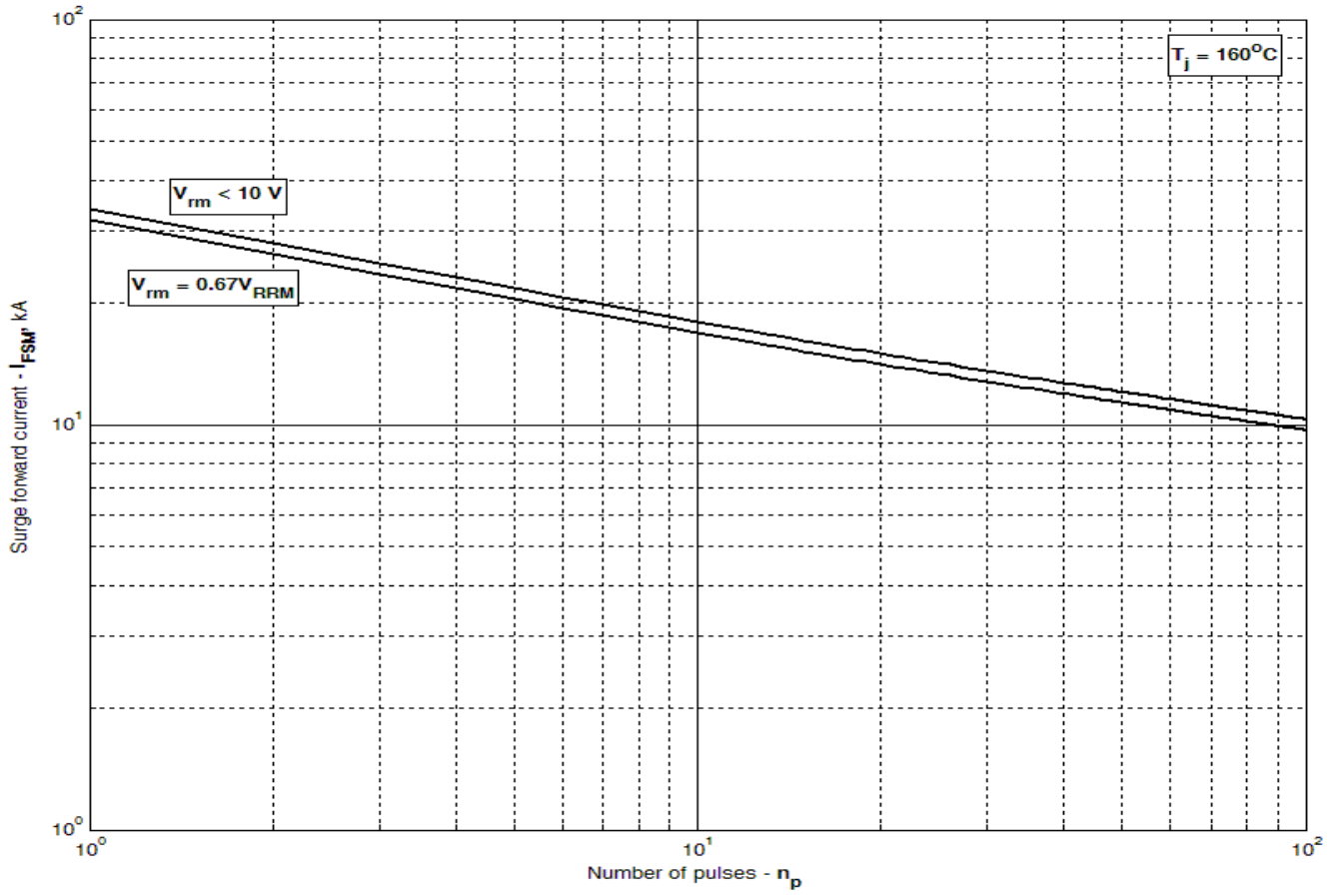


Fig 12 – Maximum surge ratings